

Notice of References Cited		Application/Control No.	Applicant(s)/Patent Under Reexamination	
		10/743,254	YAMADA ET AL.	
Examiner		Art Unit		Page 1 of 1
Leith A. Al-Nazer		2821		

U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
*	A	US-5,652,674	07-1997	Mizuuchi et al.	359/326
*	B	US-5,838,486	11-1998	Sonoda et al.	359/332
*	C	US-6,393,172	05-2002	Brinkman et al.	385/16
*	D	US-6,839,376	01-2005	Goto, Chiaki	372/101
	E	US-			
	F	US-			
	G	US-			
	H	US-			
	I	US-			
	J	US-			
	K	US-			
	L	US-			
	M	US-			

FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N	JP 01-207985 A	08-1989	Japan	Ikeda	H01S 3/18
	O	JP 51-100687	09-1976	Japan	Sakuma et al.	H01S 3/18
	P	JP 53-5984	01-1978	Japan	Piitaa	H01S 3/19
	Q	JP 08-211342 A	08-1996	Japan	Takano et al.	H01S 3/18
	R	JP 55-11400 A	01-1980	Japan	Donarudo et al.	H01S 3/18
	S					
	T					

NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	Gerard A. Alphonse et al., "High-Power Superluminescent Diodes", IEEE Journal of Quantum Electronics, Vol. 24, No. 12, December 1998, pages 2454-2457.
	V	
	W	
	X	

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.